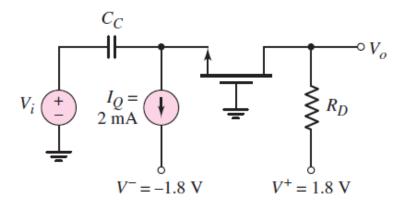
ECE322L -Homework 3 (100 points) Assigned on Thursday, 02/13/2020-11 am Due on Thursday, 02/20/2020-11 am

The transistor parameters of the NMOS in the figure below are $V_{TN} = 0.4 \text{ V}$, k = 100 $\mu\text{A/V}^2$, and $\lambda = 0$.

- (a) Determine R_D such that $V_{DSQ} = V_{DS(sat)} + 0.25 \text{ V}$.
- (b) Determine the transistor W/L ratio such that the total small-signal voltage gain is Av = 6 V/V.
- (c) What is the value of V_{GSO} ?
- (d) What are the input and the output resistance of the amplifier?
- (e) Please, comment on the performance of the circuit below as a voltage amplifier. In solving the problem, you should use the MOSFET equations provided in the Neamen book. Assume a midband frequency for the input signal.



(a)
$$V_O = (V_{DS}(sat) + 0.25) - V_{GS}$$

 $V_O = V_{GS} - V_{TN} + 0.25 - V_{GS} = -0.4 + 0.25 = -0.15 \text{ V}$
 $R_D = \frac{1.8 - (-0.15)}{2} = 0.975 \text{ k}\Omega$

(b)
$$A_{\nu} = g_{m}R_{D}$$

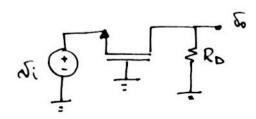
 $6 = g_{m}(0.975) \Rightarrow g_{m} = 6.154 \text{ mA/V}$
 $g_{m} = 2\sqrt{\left(\frac{k'_{n}}{2}\right)\left(\frac{W}{L}\right)}I_{DQ}$
 $6.154 = 2\sqrt{\left(\frac{0.1}{2}\right)\left(\frac{W}{L}\right)}(2) \Rightarrow \left(\frac{W}{L}\right) = 94.7$

(c)
$$I_{DQ} = \left(\frac{k'_n}{2}\right) \left(\frac{W}{L}\right) (V_{GSQ} - V_{TN})^2$$

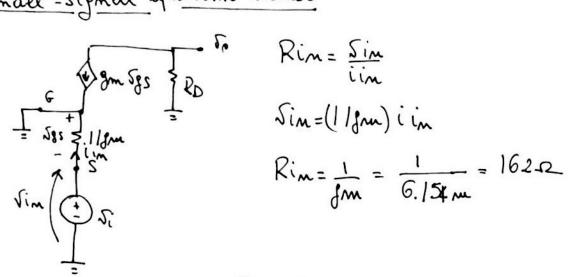
 $2 = \left(\frac{0.1}{2}\right) (94.7) (V_{GSQ} - 0.4)^2 \Rightarrow V_{GSQ} = 1.05 \text{ V}$

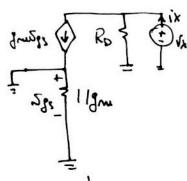
ECE 322L, Spring 2020, Instructor: Francesca Cavallo

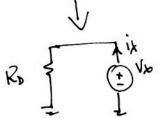
ac circuit



Small-signal equivalent circuit







e) The circuit has a positive gain, which is also large than IVIV. This is a desided attribute for a soltage somblifier. The Small imput resistance and the moderate output resistance and the moderate output resistance limit the circuit performance us a soltage amplifier as they don't allow an efficient transfer of the signal to the imput port of the surplifier and of the output Signal to a land, respectively.